

HS0038B4D

Vishay Semiconductors

IR Receiver Modules for Remote Control Systems



MECHANICAL DATA

Pinning for HS0038B4D: 1 = OUT, 2 = GND, $3 = V_S$

FEATURES

- Very low supply current
- Photo detector and preamplifier in one package
- Internal filter for PCM frequency
- Improved shielding against EMI
- Supply voltage: 2.5 V to 5.5 V
- Improved immunity against ambient light
- · Insensitive to supply voltage ripple and noise

DESCRIPTION

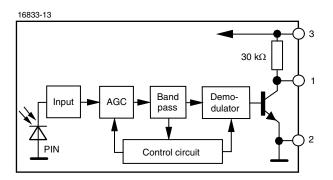
These products are miniaturized receivers for infrared remote control systems. A PIN diode and a preamplifier are assembled on a lead frame, the epoxy package acts as an IR filter.

The demodulated output signal can be directly decoded by a microprocessor. The HS0038B4D is optimized to suppress almost all spurious pulses from energy saving fluorescent lamps but will also suppress some data signals.

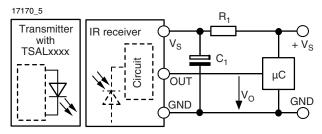
This component has not been qualified according to automotive specifications.

PARTS TABLE				
CARRIER FREQUENCY	VERY NOISY ENVIRONMENTS (AGC4)			
	PINNING			
	1 = OUT, 2 = GND, 3 = V _S			
38 kHz	HS0038B4D			

BLOCK DIAGRAM



APPLICATION CIRCUIT



 R_1 and C_1 are recommended for protection against EOS. Components should be in the range of 33 Ω < R_1 < 1 k Ω , C_1 > 0.1 $\mu F.$

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Pb-free

RoHS

COMPLIANT

GREEN (5-2008)



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ABSOLUTE MAXIMUM RATINGS							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
Supply voltage		V _S	- 0.3 to + 6	V			
Supply current		I _S	3	mA			
Output voltage		Vo	- 0.3 to (V _S + 0.3)	V			
Output current		Ι _Ο	5	mA			
Junction temperature		Tj	100	°C			
Storage temperature range		T _{stg}	- 25 to + 85	°C			
Operating temperature range		T _{amb}	- 25 to + 85	°C			
Power consumption	$T_{amb} \le 85 \ ^{\circ}C$	P _{tot}	10	mW			
Soldering temperature	$t \le 10$ s, 1 mm from case	T _{sd}	260	°C			

Note

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only
and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification
is not implied. Exposure to absolute maximum rating conditions for extended periods may affect the device reliability.

ELECTRICAL AND OPTICAL CHARACTERISTICS ($T_{amb} = 25 \text{ °C}$, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply current	$E_v = 0, V_S = 3.3 V$	I _{SD}	0.27	0.35	0.45	mA
	$E_v = 40$ klx, sunlight	I _{SH}		0.45		mA
Supply voltage		VS	2.5		5.5	V
Transmission distance	$E_v = 0$, test signal see fig. 1, IR diode TSAL6200, $I_F = 200 \text{ mA}$	d		45		m
Output voltage low	$I_{OSL} = 0.5 \text{ mA}, E_e = 0.7 \text{ mW/m}^2,$ test signal see fig. 1	V _{OSL}			100	mV
Minimum irradiance	Pulse width tolerance: t _{pi} - 5/f _o < t _{po} < t _{pi} + 6/f _o , test signal see fig. 1	E _{e min.}		0.12	0.25	mW/m ²
Maximum irradiance	t _{pi} - 5/f _o < t _{po} < t _{pi} + 6/f _o , test signal see fig. 1	E _{e max.}	30			W/m ²
Directivity	Angle of half transmission distance	φ1/2		± 45		deg

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

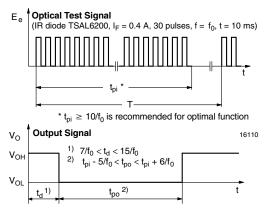


Fig. 1 - Output Active Low

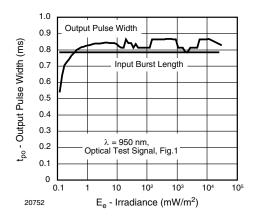


Fig. 2 - Pulse Length and Sensitivity in Dark Ambient

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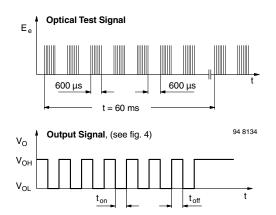


Fig. 3 - Output Function

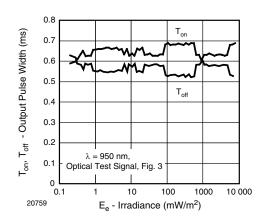


Fig. 4 - Output Pulse Diagram

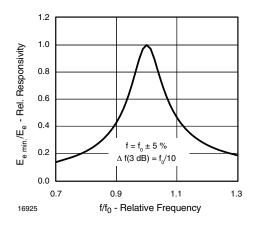


Fig. 5 - Frequency Dependence of Responsivity



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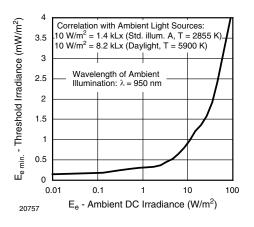


Fig. 6 - Sensitivity in Bright Ambient

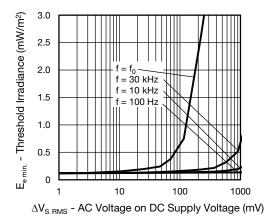
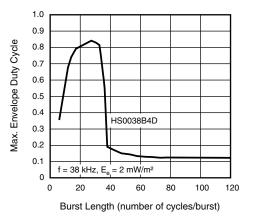
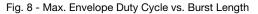


Fig. 7 - Sensitivity vs. Supply Voltage Disturbances





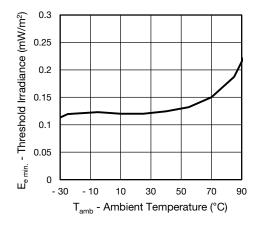
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Fig. 9 - Sensitivity vs. Ambient Temperature

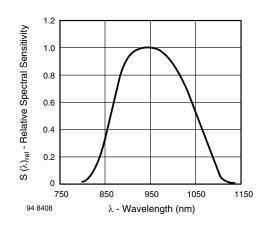


Fig. 10 - Relative Spectral Sensitivity vs. Wavelength

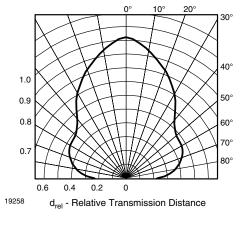


Fig. 11 - Horizontal Directivity

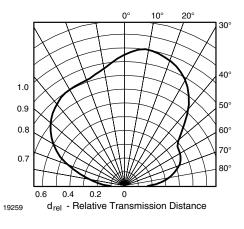


Fig. 12 - Vertical Directivity

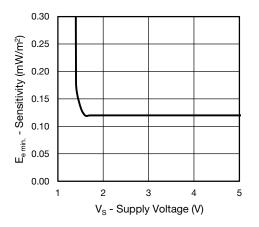


Fig. 13 - Sensitivity vs. Supply Voltage



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SUITABLE DATA FORMAT

These products are designed to suppress spurious output pulses due to noise or disturbance signals. Data and disturbance signals can be distinguished by the devices according to carrier frequency, burst length and envelope duty cycle. The data signal should be close to the band-pass center frequency (e.g. 38 kHz) and fulfill the conditions in the table below.

When a data signal is applied to the IR receiver in the presence of a disturbance signal, the sensitivity of the receiver is reduced to insure that no spurious pulses are present at the output. Some examples of disturbance signals which are suppressed are:

- DC light (e.g. from tungsten bulb or sunlight)
- Continuous signals at any frequency
- Strongly or weakly modulated noise from fluorescent lamps with electronic ballasts (see figure 15 or figure 16)

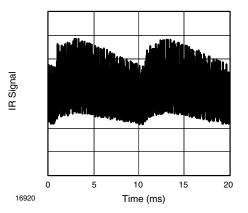


Fig. 14 - IR Signal from Fluorescent Lamp with Low Modulation

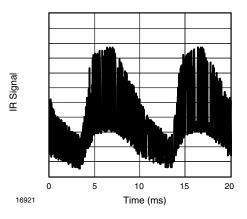


Fig. 15 - IR Signal from Fluorescent Lamp with High Modulation

	HS0038B4D		
Minimum burst length	10 cycles/burst		
After each burst of length a minimum gap time is required of	10 to 35 cycles ≥ 10 cycles		
For bursts greater than a minimum gap time in the data stream is needed of	35 cycles > 10 x burst length		
Maximum number of continuous short bursts/second	1500		
Recommended for NEC code	yes		
Recommended for RC5/RC6 code	yes		
Recommended for Sony code	no		
Recommended for Thomson 56 kHz code	yes		
Recommended for Mitsubishi code (38 kHz, preburst 8 ms, 16 bit)	no		
Recommended for Sharp code	yes		
Suppression of interference from fluorescent lamps	Even extreme disturbance signals are suppressed		



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PACKAGE DIMENSIONS in millimeters

